A uniform Tits alternative for endomorphisms of the projective line

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Abstract

The recent article [BHPT24] establishes an analog of the Tits alternative for semigroups of endomorphisms of the projective line. The proof involves a ping-pong argument on arithmetic height functions. Extending this method, we obtain a uniform version of the same alternative. In particular, we show that semigroups of $\text{End}(\mathbb{P}^1)$ of exponential growth are of uniform exponential growth.

1 Introduction

Let \mathbb{K} be an algebraically closed field and let V be a projective variety over \mathbb{K} . We denote by $\operatorname{End}(V)$ the set of endomorphisms of V defined over \mathbb{K} , which has the structure of a semigroup when endowed with the composition operation. Which types of growth rate can occur for finitely generated subsemigroups of $\operatorname{End}(V)$, and how to characterize semigroups of a given growth rate? This is a natural generalization of the study of finitely generated linear semigroups, an overview of which can be found in [Okn98].

For any $f \in \operatorname{End}(V)$, let $\operatorname{PrePer}(f)$ be its set of *preperiodic points*, that is, the set of points $z \in V(\mathbb{K})$ whose orbits under the iteration of f are finite. An endomorphism $f \in \operatorname{End}(V)$ is said to be *polarized* by an ample line bundle \mathcal{L} if $f^*\mathcal{L} \cong \mathcal{L}^{\otimes d}$ for some $d \in \mathbb{Z}_{\geq 2}$. The integer d is called the *algebraic degree* of f. The notion of polarized endomorphisms was introduced in [Zha95]. Such an endomorphism is also finite (see [Ser60], and [Fak03, §5] for the case of positive characteristic).

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The purpose of this note is to prove the following result:

Theorem 1.1. Let $f_1, f_2 \in \text{End}(V)$ be polarized by the same line bundle and suppose that $\text{PrePer}(f_1) \neq \text{PrePer}(f_2)$. Then f_1 and f_2 generate a free semigroup of rank 2.

This theorem is proven using a ping-pong argument on *height functions*, which will be introduced in Section 3. The argument used is essentially a refinement of the methods in [BHPT24, \S 3], and answers Question 5.1 of the same article.

Theorem 1.1 allows us to obtain results concerning uniform independence and uniform exponential growth for certain subsemigroups of End(V). These results are best stated using the following definitions:

Let S be any semigroup. Two elements of S are said to be *independent* if they generate a free semigroup of rank 2. For any non-empty finite subset $F \subset S$, we define the *diameter of independence* of F as

 $\Delta(F) := \inf \{ n \in \mathbb{Z}_{\geq 1} \mid F \cup F^2 \cup \dots \cup F^n \text{ contains two independent elements} \}$

where $F^n = \{f_1 \cdots f_n; f_i \in F\}$. The algebraic entropy of F is defined as

$$\Sigma(F) := \lim_{n \to \infty} \frac{1}{n} \log \# (F \cup F^2 \cup \dots \cup F^n).$$

Note that $\Delta(F)$ may be infinite, whereas $\Sigma(F)$ is always finite. Moreover, we have the following inequality:

$$\Sigma(F) \ge \log(2) / \Delta(F). \tag{1}$$

If S is finitely generated, its diameter of independence and its algebraic entropy are respectively defined as

$$\Delta(S) := \sup_{F} \Delta(F) \text{ and } \Sigma(S) := \inf_{F} \Sigma(F)$$

where F ranges over all finite generating sets of S. The semigroup S is of exponential growth if $\Sigma(F) > 0$ for some (equivalently, for any) finite generating set F of S; it is of uniform exponential growth if $\Sigma(S) > 0$.

In order to accomodate for automorphisms, we introduce the following notion: $f \in \text{End}(V)$ is *semi-polarized* by \mathcal{L} if $f^*\mathcal{L} \cong \mathcal{L}^{\otimes d}$ for some $d \in \mathbb{Z}_{\geq 1}$. In particular, we allow d = 1.

Theorem 1.2. Let V be a projective variety over an algebraically closed field \mathbb{K} . Let S be a finitely generated subsemigroup of endomorphisms of V, all semi-polarized by the same line bundle. Suppose there are $f_1, f_2 \in S$ of algebraic degree at least 2 such that $\operatorname{PrePer}(f_1) \neq \operatorname{PrePer}(f_2)$. Then $\Delta(S) \leq 2$. In particular, S is of uniform exponential growth: $\Sigma(S) \geq \log(2)/2$.

In the case where $\operatorname{char}(\mathbb{K}) = 0$ and $V = \mathbb{P}^1$, we may combine Theorem 1.2 with [BHPT24, Proposition 4.10], along with results of E. Breuillard and T. Gelander [BG05] in the linear case, to obtain the following

Theorem 1.3. Let S be a finitely generated subsemigroup of $\operatorname{End}(\mathbb{P}^1)$ over a field of characteristic 0. Then either S is of polynomial growth, or $\Delta(S) < +\infty$. In particular, semigroups of exponential growth in $\operatorname{End}(\mathbb{P}^1)$ are of uniform exponential growth.

2 A ping-pong lemma for contractions

The notions introduced in this section are presented in greater detail in the book [Fal85]. The setting of the book is Euclidean space, but the results still hold in the generality in which we use them.

Let (X, d) be a non-empty complete metric space, in which we fix a base point x_0 . A map $\alpha : X \to X$ is called a *contraction with ratio* $c \in]0, 1[$ if

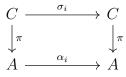
$$\forall x, y \in X, \ d(\alpha(x), \alpha(y)) \le c \cdot d(x, y).$$

By Banach's fixed point theorem, α has a unique fixed point in X. We denote by $\operatorname{Con}(X)$ the set of contractions on X, a semigroup when endowed with the composition operation. For any subset $F \subset \operatorname{Con}(X)$, we denote by $\langle F \rangle$ the subsemigroup generated by F.

The attractor. Let α_1, α_2 be two contractions with ratios c_1, c_2 , and let $C = \{\alpha_1, \alpha_2\}^{\mathbb{N}}$. For any sequence $u = (\alpha_{n_i})_{i \geq 0} \in C$, the sequence $((\alpha_{n_0} \cdots \alpha_{n_i})(x_0))_{i \geq 0}$ is Cauchy, and therefore converges to an element x_u in X. If we endow C with the product topology, the map

$$\pi: C \to X, \ u \mapsto x_u \tag{2}$$

is continuous: its image A is therefore a compact subset of X. The set A is called the *attractor* associated with the system $\{\alpha_1, \alpha_2\}$. For $i \in \{1, 2\}$, we have a commutative diagram



where $\sigma_i : (\alpha_{n_0}, \alpha_{n_1}, \cdots) \mapsto (\alpha_i, \alpha_{n_0}, \alpha_{n_1}, \cdots)$. Since $C = \sigma_1(C) \cup \sigma_2(C)$, A satisfies the self-similarity relation $A = \alpha_1(A) \cup \alpha_2(A)$. It is in fact the unique non-empty compact set that satisfies this relation (see [Fal85, §8.3]). For any subset $Y \subset X$, we denote its diameter by diam(Y). The one-dimensional Hausdorff measure of Y is defined as follows (see [Fal85, §1.2]):

$$H^{1}(Y) = \lim_{\varepsilon \to 0} \inf \left\{ \sum_{i} \operatorname{diam}(U_{i}) \mid Y \subset \bigcup_{i} U_{i}, \ 0 < \operatorname{diam}(U_{i}) \le \varepsilon \right\}$$

Proposition 2.1. Let $\alpha_1, \alpha_2 : X \to X$ be two injective contractions with ratios $c_1, c_2 \in]0, 1[$. Suppose that α_1 and α_2 have distinct fixed points and $c_1 + c_2 \leq 1$. Then $\langle \alpha_1, \alpha_2 \rangle$ is a free semigroup of rank 2.

Proof. Let A be the attractor associated with $\{\alpha_1, \alpha_2\}$ and $\pi : C \to A$ be the map introduced in equation (2). The first step of the proof is adapted from [BH85].

Step 1. Suppose that A is disconnected. We will prove that $\alpha_1(A) \cap \alpha_2(A) = \emptyset$ and conclude that $\langle \alpha_1, \alpha_2 \rangle$ is free of rank 2.

Since A is disconnected, there are non-empty compact subsets A_1, A_2 such that $A_1 \cup A_2 = A$ and $A_1 \cap A_2 = \emptyset$. By the compactness of A,

inf
$$\{d(x_1, x_2); x_1 \in A_1, x_2 \in A_2\} =: \delta > 0.$$

For $u_1, u_2 \in C$, let $\lambda(u_1, u_2)$ be their largest common prefix, and consider the set $\mathcal{P} = \{\lambda(u_1, u_2); (u_1, u_2) \in \pi^{-1}(A_1) \times \pi^{-1}(A_2)\}$. If we choose an integer $n \geq 0$ such that $\delta \geq (\max(c_1, c_2))^n \cdot \operatorname{diam}(A)$, then the words in \mathcal{P} are of length at most n. We may therefore choose a prefix $p \in \mathcal{P}$ of maximal length, as well as a pair $(pu_1, pu_2) \in \pi^{-1}(A_1) \times \pi^{-1}(A_2)$. If there existed an element $y \in \alpha_1(A) \cap \alpha_2(A)$, say

$$y = \pi(\alpha_1 v_1) = \pi(\alpha_2 v_2),$$

then without loss of generality, $p(y) = \pi(p\alpha_1v_1) = \pi(p\alpha_2v_2) \in A_1$, and pu_2 would have a common prefix with either $p\alpha_1v_1$ or $p\alpha_2v_2$ which would be longer than p, contradicting its maximality. We deduce that $\alpha_1(A) \cap \alpha_2(A) = \emptyset$.

This allows us to perform a ping-pong argument. Suppose there is a pair of distinct words w_1, w_2 in the alphabet $\{\alpha_1, \alpha_2\}$ such that $w_1 = w_2$ in $\langle \alpha_1, \alpha_2 \rangle$. Since α_1 and α_2 are injective, left cancellation implies that $\alpha_1 w'_1 = \alpha_2 w'_2$ in $\langle \alpha_1, \alpha_2 \rangle$ for some pair of words w'_1, w'_2 . But then

$$\alpha_1 w_1'(A) = \alpha_1 w_1'(A) \cap \alpha_2 w_2'(A) \subset \alpha_1(A) \cap \alpha_2(A) = \emptyset$$

which is absurd. We conclude that $\langle \alpha_1, \alpha_2 \rangle$ is free of rank 2.

Step 2. Suppose now that A is connected. We will prove that $H^1(A) = \text{diam}(A)$ and that $\alpha_1(A)$ and $\alpha_2(A)$ have an intersection of zero H^1 -measure. This will allow us to perform a measurable version of the ping-pong argument above.

By the self-similarity relation that characterizes the attractor, we have for all $n \ge 0$,

$$\bigcup_{w \in \{\alpha_1, \alpha_2\}^n} w(A) = A$$

Since α_1 and α_2 are contractions, we have

$$\operatorname{diam}(\alpha_1(A)) + \operatorname{diam}(\alpha_2(A)) \le c_1 \cdot \operatorname{diam}(A) + c_2 \cdot \operatorname{diam}(A) = (c_1 + c_2) \cdot \operatorname{diam}(A)$$

and more generally, for all $n \ge 0$,

$$\sum_{w \in \{\alpha_1, \alpha_2\}^n} \operatorname{diam}(w(A)) \le (c_1 + c_2)^n \cdot \operatorname{diam}(A).$$

This construction provides arbitrarily fine covers of A, so that $H^1(A) \leq \operatorname{diam}(A)$, and $H^1(A) = 0$ whenever $c_1 + c_2 < 1$.

Let $x, y \in A$ be such that d(x, y) = diam(A). The map

 $A \to [0, \operatorname{diam}(A)], \ z \mapsto d(x, z)$

is surjective because it is continuous and A is connected. Moreover, this map is also 1-Lipschitz, so diam $(A) = H^1([0, \text{diam}(A)]) \leq H^1(A)$ ([Fal85, Lemma 1.8]). Note that diam(A) > 0 because the fixed points of α_1 and α_2 are distinct. In view of the upper bounds on $H^1(A)$ obtained above, we must have $c_1 + c_2 = 1$ and $H^1(A) = \text{diam}(A)$. Finally,

$$H^{1}(A) \leq H^{1}(\alpha_{1}(A)) + H^{1}(\alpha_{2}(A)) \leq c_{1}H^{1}(A) + c_{2}H^{1}(A) = H^{1}(A)$$

so $H^1(\alpha_1(A) \cap \alpha_2(A)) = 0.$

Suppose there is a distinct pair of words w_1, w_2 in the alphabet $\{\alpha_1, \alpha_2\}$ such that $w_1 = w_2$ in $\langle \alpha_1, \alpha_2 \rangle$. As in the first step, we may assume that $w_1 = \alpha_1 w'_1$ and $w_2 = \alpha_2 w'_2$. Let $B = w_1(A) = w_2(A)$, a connected compact subset of A. Since α_1 and α_2 are injective, B has non-zero diameter and thus $H^1(B) > 0$. But $H^1(B) = H^1(\alpha_1 w'_1(A) \cap \alpha_2 w'_2(A)) = 0$, which is absurd. We conclude that $\langle \alpha_1, \alpha_2 \rangle$ is free of rank 2.

Remark 2.2. The bound $c_1 + c_2 \leq 1$ in Proposition 2.1 is sharp. Indeed, for $n \geq 2$, let c_n be the solution in $]\frac{1}{2}, 1[$ to the equation $x + x^2 + \cdots + x^n = 1$. Then $\alpha_1 : \mathbb{R} \to \mathbb{R}, x \mapsto c_n x$ and $\alpha_2 : \mathbb{R} \to \mathbb{R}, x \mapsto c_n x + 1$ are injective contractions (similitudes, even) with common ratio c_n , but $\alpha_1 \alpha_2^n = \alpha_2 \alpha_1^n$. By increasing n, we get values of c_n that are arbitrarily close to $\frac{1}{2}$.

3 Proof of the Theorems

Heights. Let K be a finitely generated field, V a projective variety over K and \mathcal{L} an ample line bundle on V. We also fix an algebraic closure \overline{K} of K. If K has positive characteristic, we may assume that it is infinite (otherwise every endomorphism over K has the same set of preperiodic points and our theorems are vacuous). We then fix a Weil height function $h_{\mathcal{L}} : V(\overline{K}) \to \mathbb{R}$, whose construction is detailed in [BG06, §2.4]. If K is of characteristic zero, we fix a Moriwaki height function $h_{\mathcal{L}} : V(\overline{K}) \to \mathbb{R}$, first defined in [Mor00]. Note that if K is a number field, the Moriwaki height coincides with the classical Weil height. In both cases, the function $h_{\mathcal{L}}$ satisfies two properties:

Northcott property. The set $\{x \in V(\bar{K}) \mid h_{\mathcal{L}}(x) \leq a, [K(x) : K] \leq b\}$ is finite for any a, b > 0.

Functoriality. If $f \in \text{End}(V)$ is defined over K and is polarized by \mathcal{L} with algebraic degree d, then $d \cdot h_{\mathcal{L}}$ and $f^*h_{\mathcal{L}}$ differ by a bounded function.

These constructions and their properties are also summarized in [BHPT24, §3.2]. The discussion above motivates the introduction of

$$\mathcal{H}_{\mathcal{L}} := \{ h : V(\bar{K}) \to \mathbb{R} \mid ||h - h_{\mathcal{L}}||_{\infty} < +\infty \},\$$

a complete metric space when endowed with the metric $d(h_1, h_2) := ||h_1 - h_2||_{\infty}$. We also define, for any endomorphism f polarized by \mathcal{L} of algebraic degree d,

$$\alpha_f: \mathcal{H}_{\mathcal{L}} \to \mathcal{H}_{\mathcal{L}}, \ h \mapsto \frac{1}{d} f^* h$$

By the surjectivity of $f: V(\bar{K}) \to V(\bar{K})$, we have

$$\forall h_1, h_2 \in \mathcal{H}_{\mathcal{L}}, \quad \|\alpha_f(h_1) - \alpha_f(h_2)\|_{\infty} = \frac{1}{d} \|h_1 - h_2\|_{\infty}$$

so α_f is an injective contraction with ratio $\frac{1}{d}$. By Banach's fixed point theorem, α_f has a unique fixed point in $\mathcal{H}_{\mathcal{L}}$ which is called the *canonical height* h_f associated with f and \mathcal{L} . It therefore satisfies $f^*h_f = d \cdot h_f$. By the Northcott property, we have $\{x \in V(\bar{K}) \mid h_f(x) = 0\} = \operatorname{PrePer}(f)$.

Proof of Theorem 1.1. We are given two endomorphisms f_1, f_2 of a projective variety V, polarized by the same line bundle \mathcal{L} , say $f_i^* \mathcal{L} \cong \mathcal{L}^{\otimes d_i}$ with $d_i \geq 2$, and with distinct sets of preperiodic points. We may fix a finitely generated field over which f_1, f_2, V and \mathcal{L} are defined. This allows us to define the space $\mathcal{H}_{\mathcal{L}}$, as well as the maps $\alpha_1, \alpha_2 : \mathcal{H}_{\mathcal{L}} \to \mathcal{H}_{\mathcal{L}}$ associated with f_1 and f_2 . These are injective contractions with ratios $\frac{1}{d_1}, \frac{1}{d_2} \leq \frac{1}{2}$ and fixed points h_{f_1}, h_{f_2} .

Note that the preperiodic points of a polarized endomorphism are isolated, as a consequence of [Fak03, Corollary 2.2]. In particular, the points in $\operatorname{PrePer}(f_i)$ defined over our original field \mathbb{K} coincide with the points in $\operatorname{PrePer}(f_i)$ over \overline{K} . Now, since we assume that $\operatorname{PrePer}(f_1) \neq \operatorname{PrePer}(f_2)$, we obtain $h_{f_1} \neq h_{f_2}$. We can therefore apply Proposition 2.1: the semigroup generated by α_1 and α_2 is free of rank 2. Finally, any relation of the form $f_{i_1} \cdots f_{i_n} = f_{j_1} \cdots f_{j_m}$ in $\operatorname{End}(V)$ would imply a relation $\alpha_{i_n} \cdots \alpha_{i_1} = \alpha_{j_m} \cdots \alpha_{j_1}$. From this we conclude that f_1 and f_2 generate a free semigroup of rank 2.

In order to prove Theorem 1.2, we need to adapt [BHPT24, Lemma 4.5]. For any subset F of endomorphisms of V semi-polarized by the same line bundle, and any $d \ge 1$, we denote by F_d the set of elements of F of algebraic degree d, and by $F_{>d}$ the set of elements of F of algebraic degree at least d.

Lemma 3.1. Let S be a subsemigroup of End(V), all of whose elements are semipolarized by the same line bundle. Suppose there is a generating set F of S such that for any $\sigma, \tau \in F_1 \cup \{\text{id}\}$ and any $f, g \in F_{\geq 2}$, we have $\text{PrePer}(\sigma f) = \text{PrePer}(\tau g)$. Then $\text{PrePer}(w_1) = \text{PrePer}(w_2)$ for any $w_1, w_2 \in S_{\geq 2}$.

Proof. We may assume that $S_{\geq 2}$ is non-empty. Therefore $F_{\geq 2}$ is also non-empty: we fix $f \in F_{\geq 2}$ and define $P = \operatorname{PrePer}(f)$. For any $g \in F_{\geq 2}$, we may set $\sigma = \tau$ = id to obtain $P = \operatorname{PrePer}(f) = \operatorname{PrePer}(g)$. Similarly, for any $\sigma = F_1$, we have $\operatorname{PrePer}(\sigma f) = \operatorname{PrePer}(f) = P$. In particular, P is both f and σf invariant, so $\sigma(P) = \sigma f(P) = P$. Let $w \in S_{\geq 2}$. Then w is a product of elements of F, and thus w(P) = P.

Fix a finitely generated field K over which S is defined, and consider the canonical height h_f of f. We have $P = \{x \in V(\overline{K}) \mid h_f(x) = 0\}$, so by the Northcott property, all w-orbits in P are finite. In other words, $P \subset \operatorname{PrePer}(w)$. As a result of [Fak03, Theorem 5.1], P is Zariski-dense in V. Hence, we can apply [YZ21, Theorem 1.3, $(3) \Rightarrow (1)$], or [Car20, Theorem A, $(3) \Rightarrow (4)$] for the case of positive characteristic, to conclude that $P = \operatorname{PrePer}(w)$.

Proof of Theorem 1.2. Let S be a finitely generated subsemigroup of $\operatorname{End}(V)$, all of whose elements are semi-polarized by the same line bundle. Let F be any finite generating set of S. If $\operatorname{PrePer}(w_1) \neq \operatorname{PrePer}(w_2)$ for some $w_1, w_2 \in S_{\geq 2}$, then by Lemma 3.1, $\operatorname{PrePer}(\sigma f) \neq \operatorname{PrePer}(\tau g)$ for some $\sigma, \tau \in F_1 \cup \{\mathrm{id}\}$ and $f, g \in F_{\geq 2}$. Applying Theorem 1.1, we deduce that σf and τg are independent. Since $\sigma f, \tau g \in$ $F \cup F^2$, we have $\Delta(F) \leq 2$ and thus $\Delta(S) \leq 2$. In particular, using inequality (1),

$$\Sigma(S) \ge \log(2)/\Delta(S) \ge \log(2)/2 > 0,$$

so S is of uniform exponential growth.

In order to treat the linear case, we shall need the following result from E. Breuillard and T. Gelander.

Theorem 3.2 ([BG05, Theorem 2.3]). Let K be a finitely generated field, and let $n \ge 1$. There exists a constant $c(n, K) < +\infty$ such that for any subset $F \subset GL_n(K)$ that generates a non virtually nilpotent group, $\Delta(F) \le c(n, K)$.

Proof of Theorem 1.3. Let S be a finitely generated subsemigroup of $\operatorname{End}(\mathbb{P}^1)$ which is not of polynomial growth. Fix a finitely generated field K over which S is defined. Since constant maps in $\operatorname{End}(\mathbb{P}^1)$ are left-absorbing, they cannot be part of an independent pair. In other words, $\Delta(S) = \Delta(S_{\geq 1})$, so we may assume that S contains no non-constant maps.

If $S_{\geq 2}$ is non-empty, then by [BHPT24, Proposition 4.10], $\operatorname{PrePer}(f) \neq \operatorname{PrePer}(g)$ for some $f, g \in S_{\geq 2}$, and so by Theorem 1.2 we have $\Delta(S) \leq 2 < +\infty$. Suppose then that S only contains elements of degree 1. Let F be any finite generating set of S. The group generated by F in $\operatorname{PGL}_2(K)$ is not of polynomial growth, so is not virtually nilpotent ([Wol68]). By Theorem 3.2, there exists a constant $c < +\infty$ that only depends on K such that $\Delta(F) \leq c$. We conclude that $\Delta(S) \leq c < +\infty$.

In particular, if S is of exponential growth, then $\Sigma(S) \ge \log(2)/\Delta(S) > 0$ so S is of uniform exponential growth.

Remark 3.3. Note that in the case $S_{\geq 2} \neq \emptyset$, the upper bound on the diameter of independence is absolute, whereas in the linear case, it depends on the choice of semigroup. Indeed, there is no uniform upper bound on $\Delta(S)$ for all semigroups $S \subset PGL_2$ of exponential growth (see [Bre06, Theorem 1.7]; this phenomenon only occurs when S generates a virtually solvable, non virtually nilpotent group). On the other hand, the existence of a uniform lower bound on $\Sigma(S)$ for all semigroups $S \subset PGL_2$ of exponential growth is still unknown; in fact it would imply Lehmer's conjecture (see [Bre06, Question 1.8]).

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